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TOSHIBA Photocoupler Photo Relay

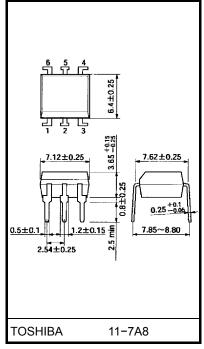
TLP798GA

Telecommunication Data Acquisition Measurement Instrumentation

The TOSHIBA TLP798GA consists of an aluminum gallium arsenide infrared emitting diode optically coupled to a photo–MOS FET in a six lead plastic DIP package (DIP6).

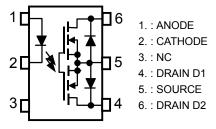
The TLP798GA is a bi-directional switch which can replace mechanical relays in many applications.

- Peak off-state voltage: 400 V (min.)
- On-state current: 150 mA (max.) (A connection)
- On-state resistance: 12 Ω (max.) (A connection)
- Isolation voltage: 5000 Vrms (min.) (A connection)
- Isolation Thickness: 0.4 mm (min.)

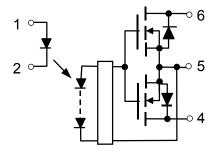


Weight: 0.4 g

Pin Configuration (top view)



Schematic



Unit in mm

Absolute Maximum Ratings (Ta = 25°C)

	Characteristic		Symbol	Rating	Unit
	Forward current	١ _F	30	mA	
	Forward current derating (Ta ≥ 25°C)	ΔI _F / °C	-0.3	mA / °C	
LED	Peak forward current (100 µs pulse, 100 pp	s)	I _{FP}	1	Α
_	Reverse voltage		V _R	5	V
	Junction temperature	Tj	125	°C	
	Off-state output terminal voltage	VOFF	400	V	
	On-state RMS current	A connection		150	
		B connection	ION	200	mA
ctor		C connection		300	
Detector	On–state current derating (Ta ≥ 25°C)	A connection	ΔI _{ON} / °C	-1.5	
		B connection		-2.0	mA / °C
		C connection		-3.0	
	Junction temperature	Тj	125	°C	
Storage temperature range			T _{stg}	-55~125	°C
Operating temperature range			T _{opr}	-40~85	°C
Lead	soldering temperature (10 s)	T _{sol}	260	°C	
Isola	tion voltage (AC, 1 min., R.H. ≤ 60%)	BVS	5000	Vrms	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

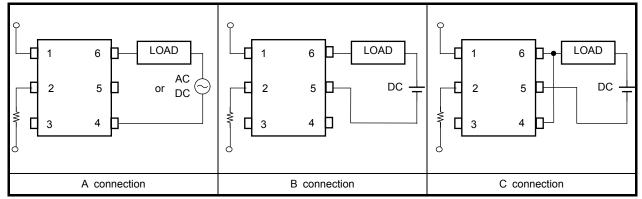
(Note 2): Device considered a two-terminal device: Pins 1, 2 and 3 shorted together, and pins 4, 5 and 6 shorted together.

Recommended Operating Conditions

Characteristic	Symbol	Min.	Тур.	Max.	Unit
Supply voltage	V _{DD}	_	_	320	V
Forward current	١ _F	5	7.5	20	mA
On-state current (A connection)	I _{ON}		—	150	mA
Operating temperature	T _{opr}	-20	_	80	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Circuit Connections



Individual Electrical Characteristics (Ta = 25°C)

	Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
	Forward voltage	V _F	I _F = 10 mA	1.18	1.33	1.48	V
LED	Reverse current	I _R	V _R = 5 V	_	_	10	μA
	Capacitance	CT	V = 0, f = 1 MHz	_	30	_	pF
ector	Off-state current	IOFF	V _{OFF} = 400 V	_	_	1	μA
Detector	Capacitance	C _{OFF}	V = 0, f = 1 MHz	_	_	_	pF

Coupled Electrical Characteristics (Ta = 25°C)

Cha	racteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Trigger LED current		I _{FT}	I _{ON} = 150 mA	—	1	3	mA
	A connection		I _{ON} = 150 mA, I _F = 5 mA	—	8	12	
On-state resistance	B connection	R _{ON}	I _{ON} = 200 mA, I _F = 5 mA	—	4	6	Ω
	C connection		I _{ON} = 300 mA, I _F = 5 mA	—	2	3	

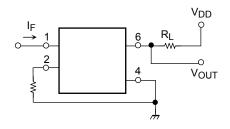
Isolation Characteristics (Ta = 25°C)

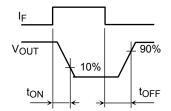
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Capacitance input to output	CS	V _S = 0, f = 1 MHz	_	0.8	_	pF
Isolation resistance	R _S	V _S = 500 V, R.H. ≤ 60%	$5 imes 10^{10}$	10 ¹⁴		Ω
		AC, 1 minute	5000	_	_	Vrms
Isolation voltage	BVS	AC, 1 second (in oil)	_	10000	_	vinis
		DC, 1 minute (in oil)	_	10000	_	V _{DC}

Switching Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Turn-on time	t _{ON}	V _{DD} = 20 V, R _L = 200 Ω	_	0.3	1.0	ms
Turn-off time	tOFF	$I_F = 5 \text{ mA}$ (Note 3)		0.2	1.0	1115

(Note 3): Switching time test circuit





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50 30

10

3

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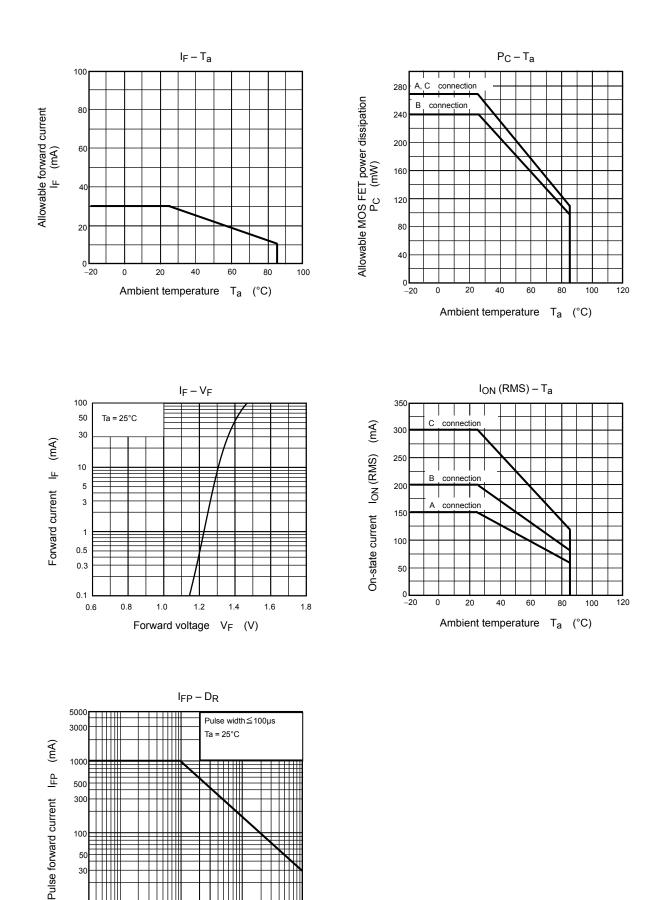
3

 10^{-2}

3

Duty cycle ratio DR

 10^{-1}



10⁰

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